

KM681000B Family

CMOS SRAM

128K x8 bit Low Power CMOS Static RAM

FEATURES

- Process Technology : 0.6μm CMOS
- Organization : 128Kx8
- Power Supply Voltage : Single 5.0V ±10%
- Low Data Retention Voltage : 2V(Min)
- Three state output and TTL Compatible
- Package Type : JEDEC Standard
32-DIP, 32-SOP, 32-TSOP I R/F

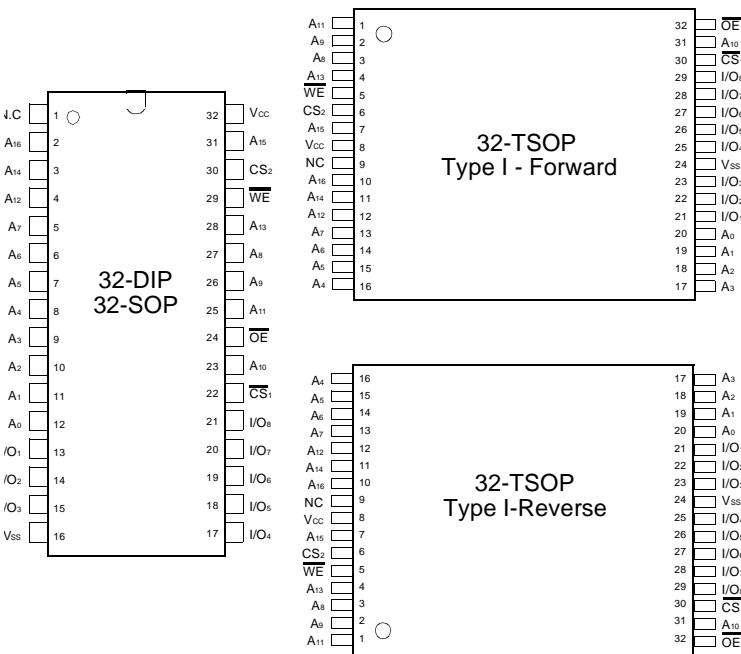
GENERAL DESCRIPTION

The KM681000B family is fabricated by SAMSUNG's advanced CMOS process technology. The family can support various operating temperature ranges and have various package types for user flexibility of system design. The family also support low data retention voltage for battery back-up operation with low data retention current.

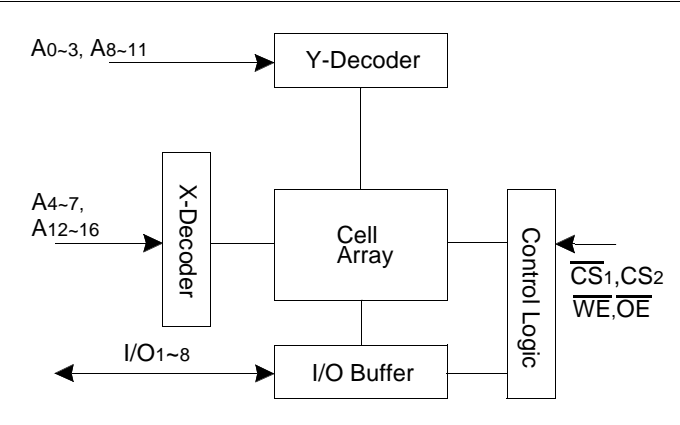
PRODUCT FAMILY

Product Family	Operating Temperature	Speed	PKG Type	Power Dissipation	
				Standby (Isb1, Max)	Operating (Icc2)
KM681000BL KM681000BL-L	Commercial(0~70°C)	55/70ns	32-DIP,32-SOP 32-TSOP I R/F	100mW 20mW	70mA
KM681000BLE KM681000BLE-L	Extended(-25~85°C)	70/100ns	32-SOP 32-TSOP I R/F	100mW 50mW	
KM681000BLI KM681000BLI-L	Industrial(-40~85°C)	70/100ns	32-SOP 32-TSOP I R/F	100mW 50mW	

PIN DESCRIPTION



FUNCTIONAL BLOCK DIAGRAM



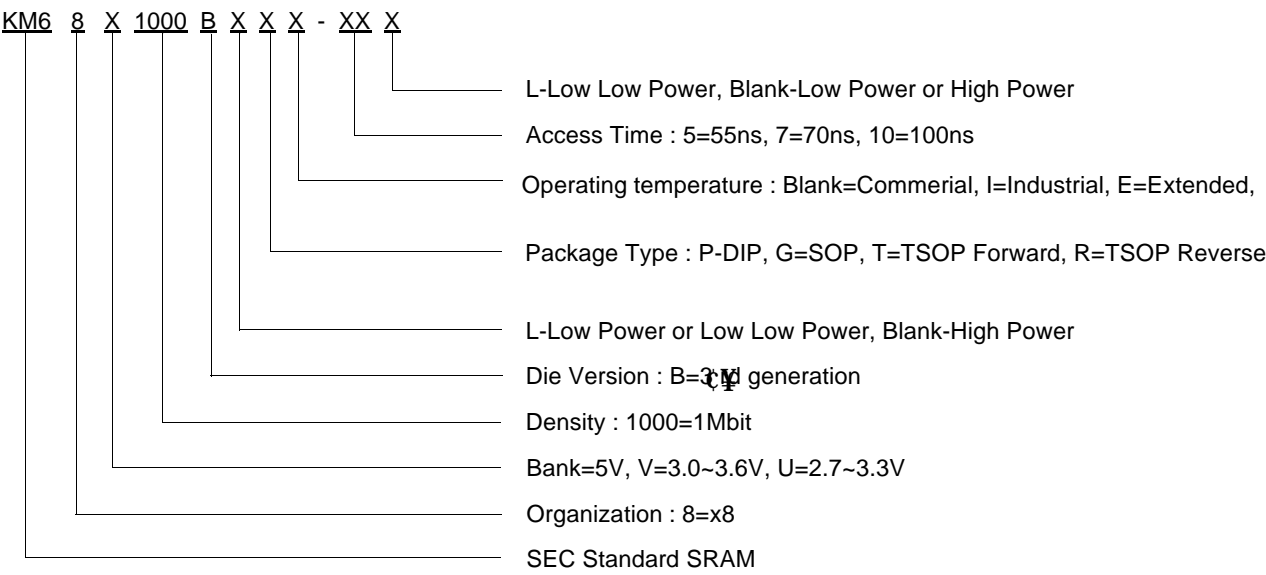
Name	Function
A0~A16	Address Inputs
\overline{WE}	Write Enable Input
$\overline{CS1}, CS2$	Chip Select Inputs
\overline{OE}	Output Enable Input
I/O1~I/O18	Data Inputs/Outputs
Vcc	Power
Vss	Ground
N.C	No Connection

PRODUCT LIST & ORDERING INFORMATION

PRODUCT LIST

Commercial Temp Product (0~70;E)		Extended Temp Products (-25~85;E)		Industrial Temp Products (-40~85;E)	
Part Name	Function	Part Name	Function	Part Name	Function
KM681000BLP-5	32-DIP,55ns,L-pwr	KM681000BLGE-7	32-SOP,70ns,L-pwr	KM681000BLGI-7	32-SOP,70ns,L-pwr
KM681000BLP-5L	32-DIP,55ns,LL-pwr	KM681000BLGE-7L	32-SOP,70ns,LL-pwr	KM681000BLGI-7L	32-SOP,70ns,LL-pwr
KM681000BLP-7	32-DIP,70ns,L-pwr	KM681000BLGE-10	32-SOP,100ns,L-pwr	KM681000BLGI-10	32-SOP,100ns,L-pwr
KM681000BLP-7L	32-DIP,70ns,LL-pwr	KM681000BLGE-10L	32-SOP,100ns,LL-pwr	KM681000BLGI-10L	32-SOP,100ns,LL-pwr
KM681000BLG-5	32-SOP,55ns,L-pwr	KM681000BLTE-7	32-TSOP F,70ns,L-pwr	KM681000BLTI-7	32-TSOP F,70ns,L-pwr
KM681000BLG-5L	32-SOP,55ns,LL-pwr	KM681000BLTE-7L	32-TSOP F,70ns,LL-pwr	KM681000BLTI-7L	32-TSOP F,70ns,LL-pwr
KM681000BLG-7	32-SOP,70ns,L-pwr	KM681000BLTE-10	32-TSOP F,100ns,L-pwr	KM681000BLTI-10	32-TSOP F,100ns,L-pwr
KM681000BLG-7L	32-SOP,70ns,LL-pwr	KM681000BLTE-10L	32-TSOP F,100ns,LL-pwr	KM681000BLTI-10L	32-TSOP F,100ns,LL-pwr
KM681000BLT-5	32-TSOP F,55ns,L-pwr	KM681000BLRE-7	32-TSOP R,70ns,L-pwr	KM681000BLRI-7	32-TSOP R,70ns,L-pwr
KM681000BLT-5L	32-TSOP F,55ns,LL-pwr	KM681000BLRE-7L	32-TSOP R,70ns,LL-pwr	KM681000BLRI-7L	32-TSOP R,70ns,LL-pwr
KM681000BLT-7	32-TSOP F,70ns,L-pwr	KM681000BLRE-10	32-TSOP R,100ns,L-pwr	KM681000BLRI-10	32-TSOP R,100ns,L-pwr
KM681000BLT-7L	32-TSOP F,70ns,LL-pwr	KM681000BLRE-10L	32-TSOP R,100ns,LL-pwr	KM681000BLRI-10L	32-TSOP R,100ns,LL-pwr
KM681000BLR-5	32-TSOP R,55ns,L-pwr				
KM681000BLR-5L	32-TSOP R,55ns,LL-pwr				
KM681000BLR-7	32-TSOP R,70ns,L-pwr				
KM681000BLR-7L	32-TSOP R,70ns,LL-pwr				

ORDERING INFORMATION



ABSOLUTE MAXIMUM RATINGS*

Item	Symbol	Ratings	Unit	Remark
Voltage on any pin relative to Vss	VIN,VOUT	-0.5 to 7.0	V	-
Voltage on Vcc supply relative to Vss	VCC	-0.5 to 7.0	V	-
Power Dissipation	Pd	1.0	W	-
Storage temperature	TSTG	-65 to 150	°C	-
Operating Temperature	TA	0 to 70	°C	KM681000BL/L-L
		-25 to 85	°C	KM681000BLE/LE-L
		-40 to 85	°C	KM681000BLI/LI-L
Soldering temperature and time	TSOLDER	260°C, 10sec (Lead Only)	-	-

* Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operating section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

RECOMMENDED DC OPERATING CONDITIONS*

Item	Symbol	Min	Typ**	Max	Unit
Supply voltage	Vcc	4.5	5.0	5.5	V
Ground	Vss	0	0	0	V
Input high voltage	VIH	2.2	-	Vcc+0.5	V
Input low voltage	VIL	-0.5***	-	0.8	V

1) Commercial Product : TA=0 to 70°C, unless otherwise specified
2) Extended Product : TA=-25 to 85°C, unless otherwise specified
3) Industrial Product : TA=-40 to 85°C, unless otherwise specified
** TA=25°C
*** VIL(min)=-3.0V for tA 50ns pulse width

CAPACITANCE* (f=1MHz, TA=25°C)

Item	Symbol	Test Condition	Min	Max	Unit
Input capacitance	CIN	Vin=0V	-	6	pF
Input/Output capacitance	CIO	Vio=0V	-	8	pF

* Capacitance is sampled not 100% tested

DC AND OPERATING CHARACTERISTICS

Item		Symbol	Test Conditions*		Mi	Typ**	Max	Unit
Input leakage current		ILI	VIN=Vss to Vcc		-1	-	1	SE
Output leakage current		ILO	CS1=VIH or CS2=VIL or WE=VIL, VIO=Vss to Vcc		-1	-	1	SE
Operating power supply current		ICC	CS1=VIL, CS2=VIH, VIN=VIH or VIL, IIO=0mA		-	7	15**	mA
Average operating current		ICC1	Cycle time=1SA 100% duty CS1j^0.2V, CS2j^AVcc-0.2V		-	-	10***	mA
		ICC2	IIO=0mA CS1=VIL,CS2=VIH Min cycle, 100% duty		-	-	70	mA
Output low voltage		VOL	IOL=2.1mA		-	-	0.4	V
Output high voltage		VOH	IOH=-1.0mA		2.4	-	-	V
Standby Current(TTL)		ISB	CS1=VIH, CS2=VIL		-	-	3	mA
Standby Current (CMOS)	KM681000BL	ISB1	CS1j^AVcc-0.2V CS2j^AVcc-0.2V or CS2j^0.2V Other input=0~Vcc	L (Low Power)	-	-	100	SE
	KM681000BL-L			LL (Low Low Power)	-	-	20	SE
	KM681000BLE			L (Low Power)	-	-	100	SE
	KM681000BLE-L			LL (Low Low Power)	-	-	50	SE
	KM681000BLI			L (Low Power)	-	-	100	SE
	KM681000BLI-L			LL (Low Low Power)	-	-	50	SE

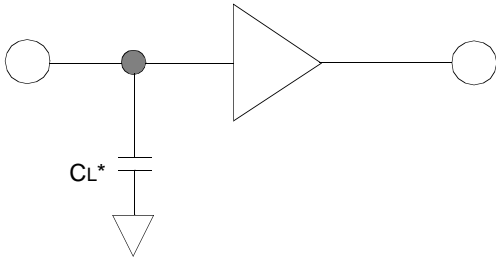
* 1) Commercial Product : TA=0 to 70°C, VCC=5.0V ±10%, unless otherwise specified
2) Extended Product : TA=-25 to 85°C, VCC=5.0V ±10%, unless otherwise specified
2) Industrial Product : TA=-40 to 85°C, VCC=5.0V ±10%, unless otherwise specified
** 20mA for Extended and Industrial Products
*** 15mA for Extended and Industrial Products

A.C CHARACTERISTICS

TEST CONDITIONS(1.Test Load and Test Input/Output Reference)*

Item	Value	Remark
Input pulse level	0.8 to 2.4V	-
Input rising & falling time	5ns	-
input and output reference voltage	1.5V	-
Output load (See right)	CL=100pF+1TTL	-

* See DC Operating conditions



* Including scope and jig capacitance

TEST CONDITIONS(2. Temperature and Vcc Conditions)

Product Family	Temperature	Power Supply(Vcc)	Speed Bin	Comments
KM681000BL/L-L	0~70jE	5.0Vj%10%	55/70ns	Commercial
KM681000BLE/LE-L	-25~85jE	5.0Vj%10%	70/100ns	Extended
KM681000BLI/LI-L	-40~85jE	5.0Vj%10%	70/100ns	Industrial

PARAMETER LIST FOR EACH SPEED BIN

Parameter List		Symbol	Speed Bins						Units
			55ns		70ns		100ns		
			Min	Max	Min	Max	Min	Max	
Read	Read cycle time	tRC	55	-	70	-	100	-	ns
	Address access time	tAA	-	55	-	70	-	100	ns
	Chip select to output	tCO1,tCO2	-	55	-	70	-	100	ns
	Output enable to valid output	tOE	-	25	-	35	-	50	ns
	Chip select to low-Z output	tLZ1,tLZ2	10	-	10	-	10	-	ns
	Output enable to low-Z output	tOLZ	5	-	5	-	5	-	ns
	Chip disable to high-Z output	tHZ1,tHZ2	0	20	0	25	0	30	ns
	Output disable to high-Z output	tOHZ	0	20	0	25	0	30	ns
	Output hold from address change	tOH	10	-	10	-	10	-	ns
Write	Write cycle time	tWC	55	-	70	-	100	-	ns
	Chip select to end of write	tCW	45	-	60	-	80	-	ns
	Address set-up time	tAS	0	-	0	-	0	-	ns
	Address valid to end of write	tAW	45	-	60	-	80	-	ns
	Write pulse width	tWP	40	-	50	-	60	-	ns
	Write recovery time	tWR	0	-	0	-	0	-	ns
	Write to output high-Z	tWHZ	0	20	0	25	0	30	ns
	Data to write time overlap	tDW	25	-	30	-	40	-	ns
	Data hold from write time	tDH	0	-	0	-	0	-	ns
	End write to output low-Z	tOW	5	-	5	-	5	-	ns

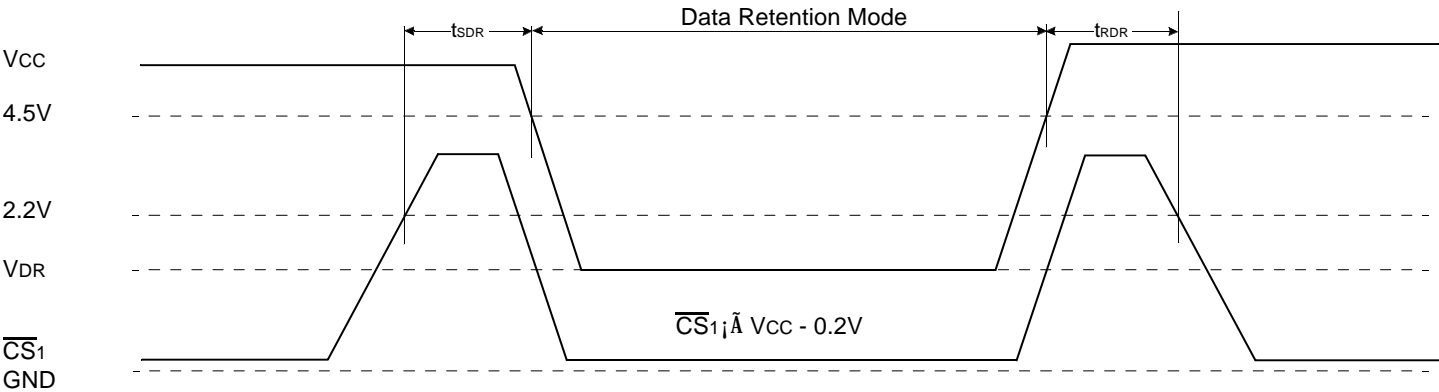
DATA RETENTION CHARACTERISTICS

Item	Symbol		Test Condition*		Min	Typ**	Max	Unit
Vcc for data retention	VDR		$\overline{CS}_1^{***} \hat{A} V_{cc}-0.2V$		2.0	-	5.5	V
Data retention current	IDR	KM681000BL KM681000BL-L	$V_{cc}=3.0V$ $\overline{CS}_1 \hat{A} V_{cc}-0.2V$	L-Ver LL-Ver	- -	1 0.5	50 10	μA
		KM681000BLE KM681000BLE-L		L-Ver LL-Ver	- -	- -	50 25	
		KM681000BLI KM681000BLI-L		L-Ver	-	-	50	
				LL-Ver	-	-	25	
Data retention set-up time	tRDR		See data retention waveform		0	-	-	ms
Recovery time	tRDR				5	-	-	

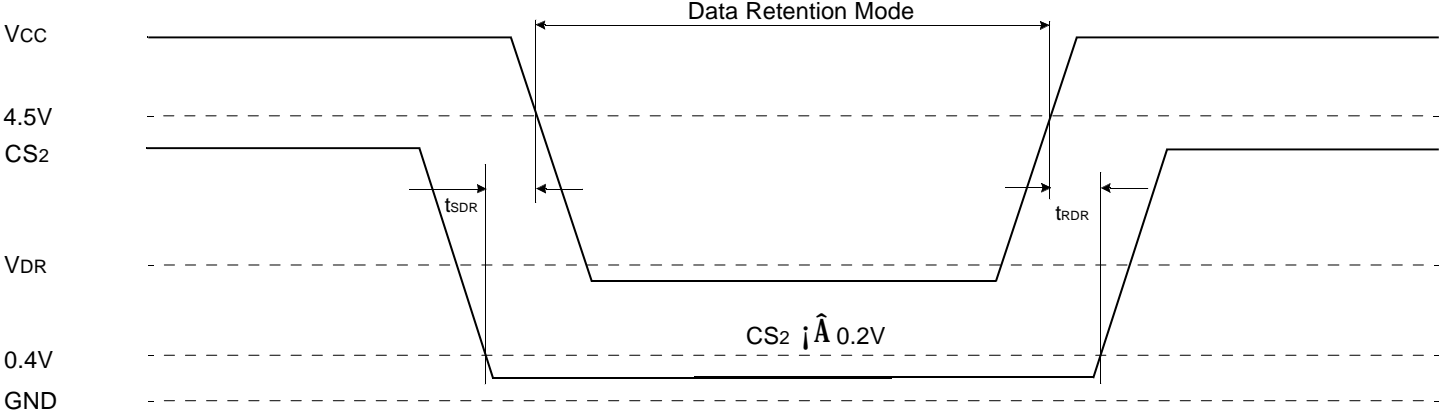
* 1) Commercial Product : TA=0 to 70 \hat{C} , unless otherwise specified
 2) Extended Product : TA=-25 to 85 \hat{C} , unless otherwise specified
 2) Industrial Product : TA=-40 to 85 \hat{C} , unless otherwise specified
 ** TA=25 \hat{C}
 *** $\overline{CS}_1 \hat{A} V_{CC}-0.2V, CS_2 \hat{A} V_{CC}-0.2V(\overline{CS}_1 \text{ controlled})$ or $CS_2 \hat{A} 0.2V(CS_2 \text{ controlled})$

DATA RETENTION TIMING DIAGRAM

1) \overline{CS}_1 Controlled

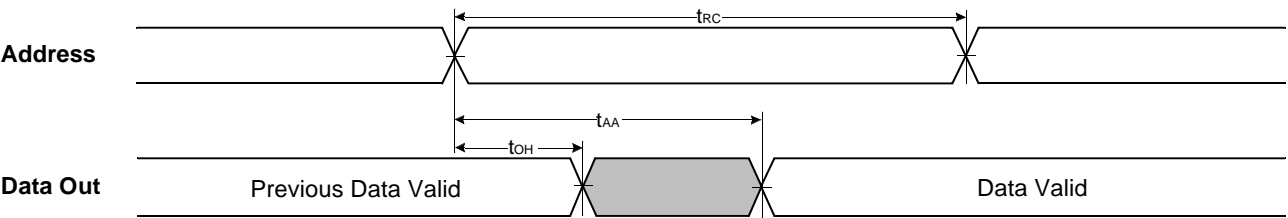


2) \overline{CS}_2 controlled

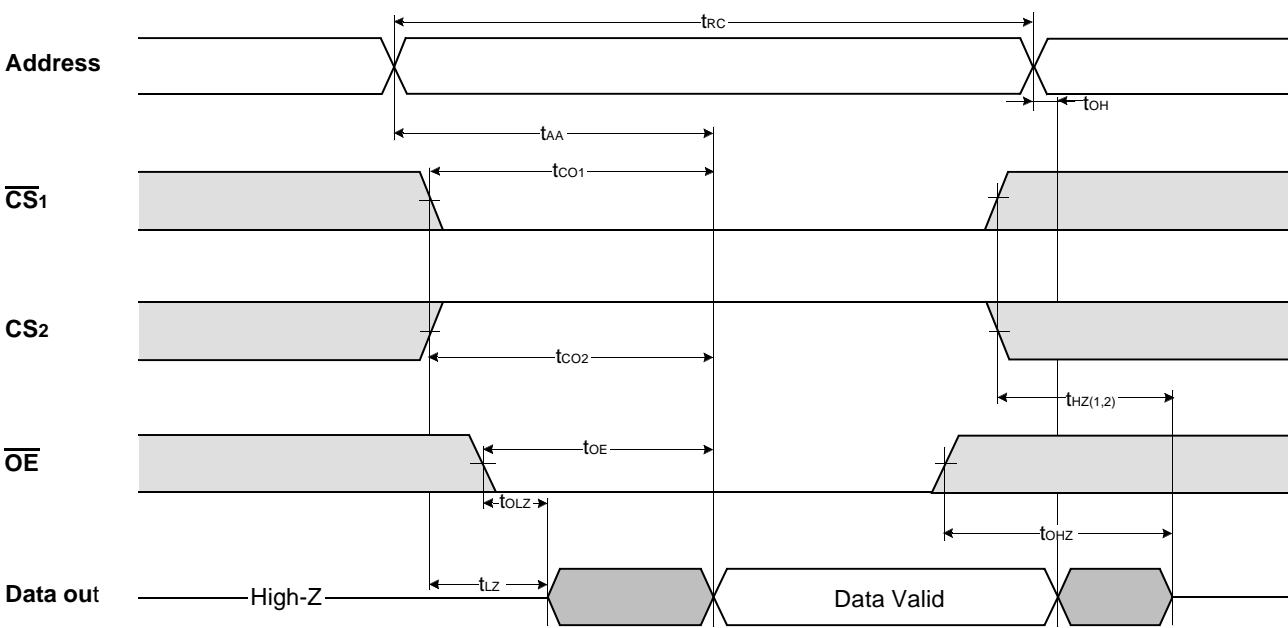


TIMMING DIAGRAMS

TIMING WAVEFORM OF READ CYCLE (1)
 (Address Controlled)
 ($\overline{CS_1}=\overline{OE}=V_{IL}$, $CS_2=\overline{WE}=V_{IH}$)



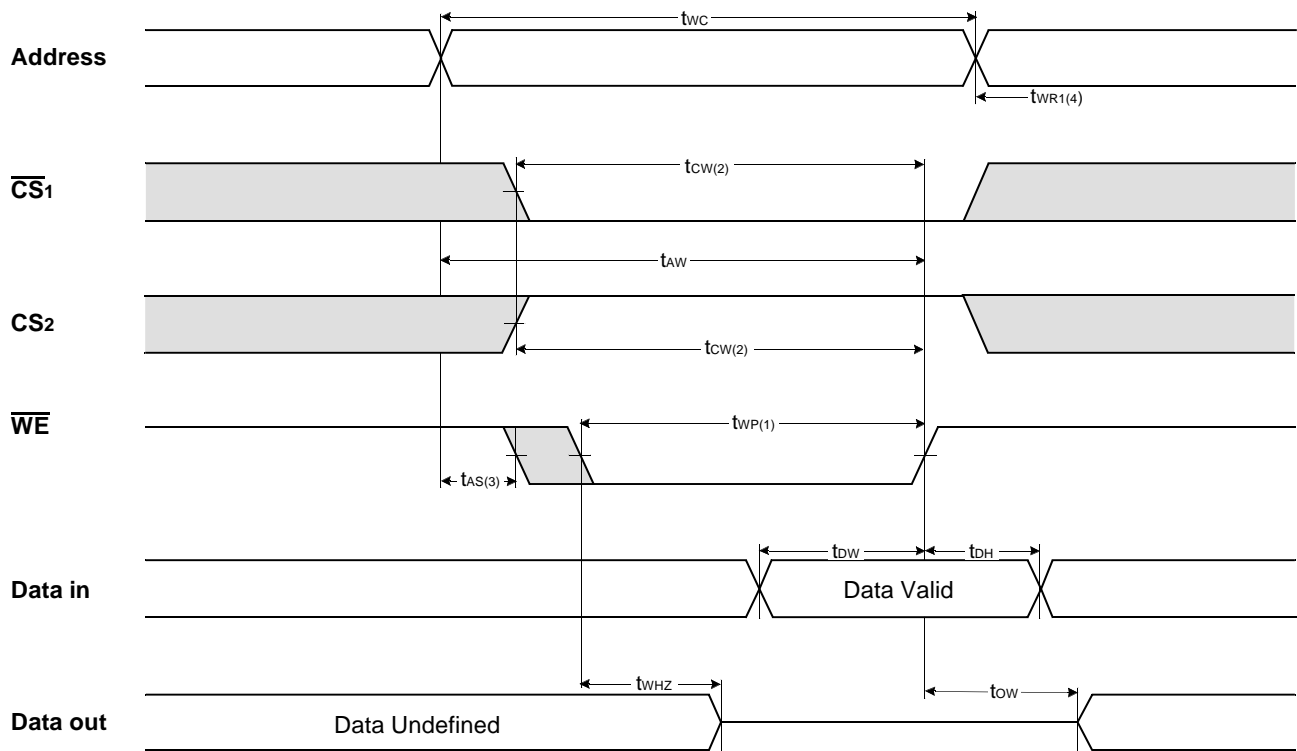
TIMING WAVEFORM OF READ CYCLE (2)
 ($\overline{WE}=V_{IH}$)



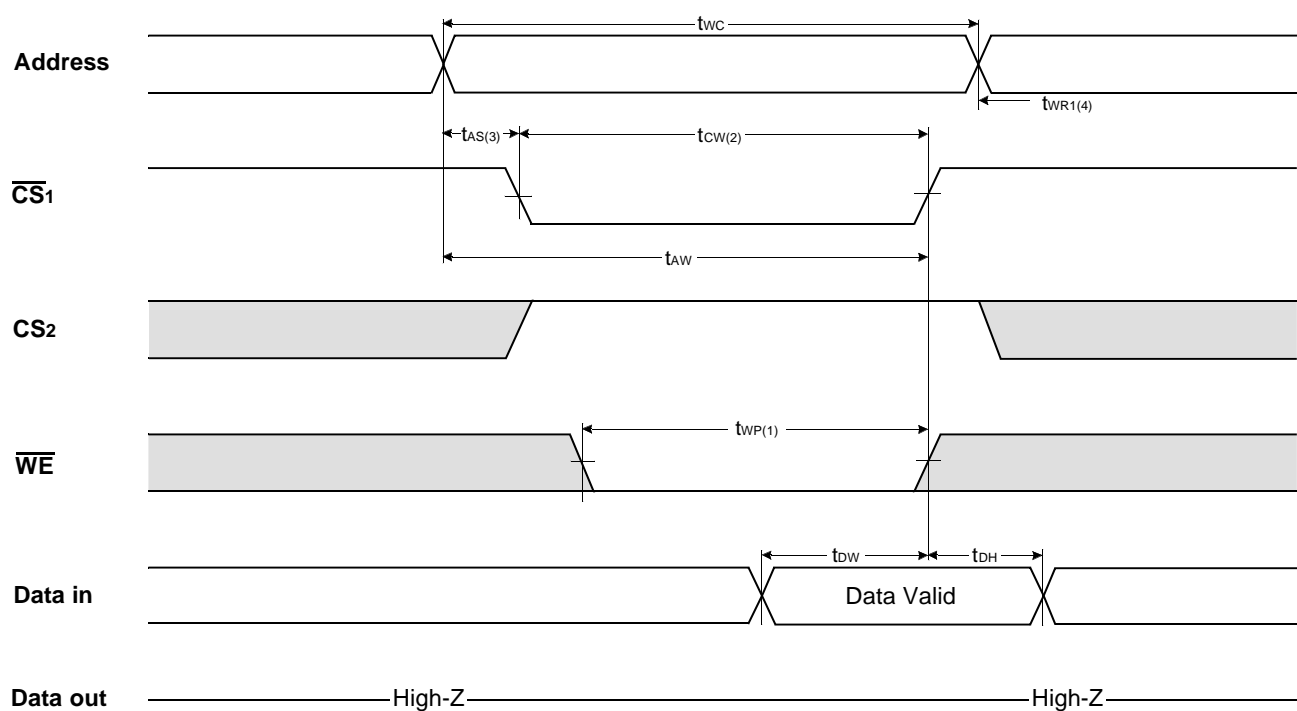
NOTES (READ CYCLE)

- 1. t_{HZ} and t_{OHZ} are defined as the time at which the outputs achieve the open circuit conditions and are not referenced to output voltage levels.
- 2. At any given temperature and voltage condition, $t_{HZ}(\text{max.})$ is less than $t_{LZ}(\text{min.})$ both for a given device and from device to device.

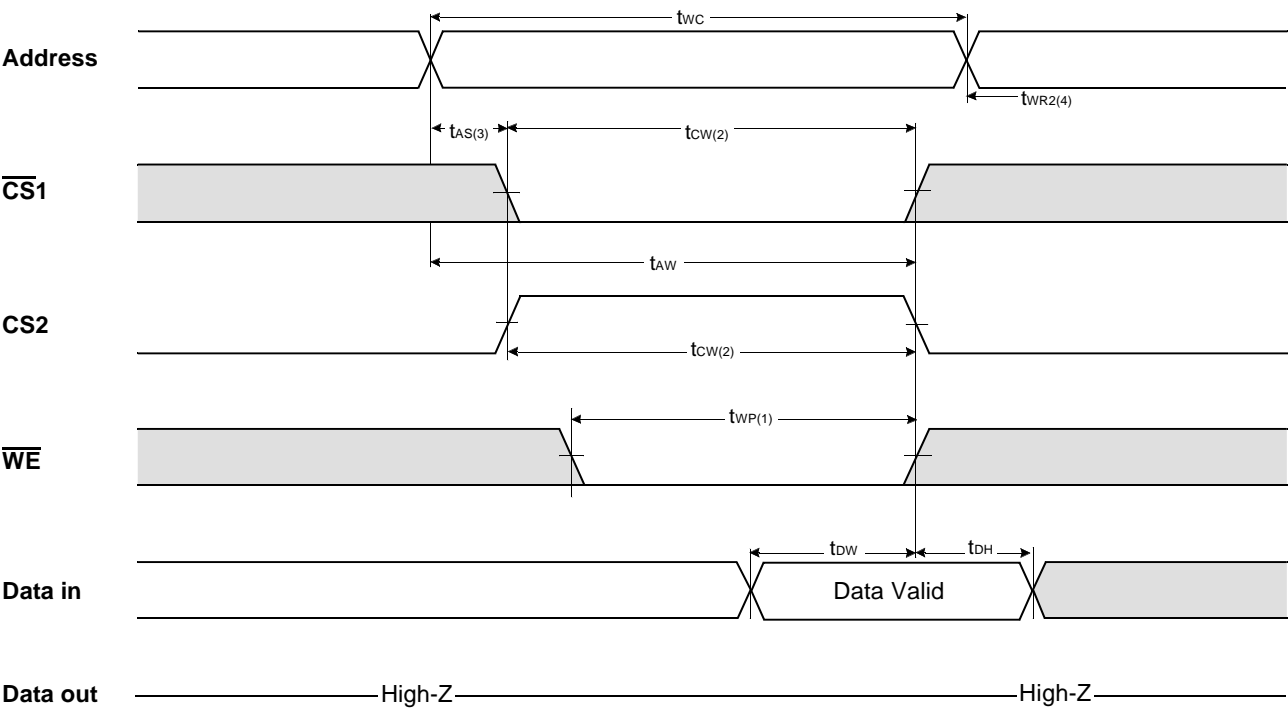
TIMING WAVEFORM OF WRITE CYCLE (1) \overline{WE} Controlled



TIMING WAVEFORM OF WRITE CYCLE (2) $\overline{CS_1}$ Controlled



TIMING WAVEFORM OF WRITE CYCLE (2 $\overline{CS_2}$ Controlled)



- NOTES (WRITE CYCLE)**
1. A write occurs during the overlap of low $\overline{CS_1}$, high $\overline{CS_2}$ and low \overline{WE} . A write begins at the latest transition among $\overline{CS_1}$ going low, $\overline{CS_2}$ going high and \overline{WE} going low. A write ends at the earliest transition among $\overline{CS_1}$ going high, $\overline{CS_2}$ going low and \overline{WE} going high, t_{WP} is measured from the beginning or write to the end of write.
 2. t_{CW} is measured from the later of $\overline{CS_1}$ going low or $\overline{CS_2}$ going high to the end of write.
 3. t_{AS} is measured from the address valid to the beginning of write.
 4. t_{WR} is measured from the end of write to the address change. t_{WR1} applied in case a write ends at $\overline{CS_1}$, or \overline{WE} going high, t_{WR2} applied in case a write ends at $\overline{CS_2}$ going to low.

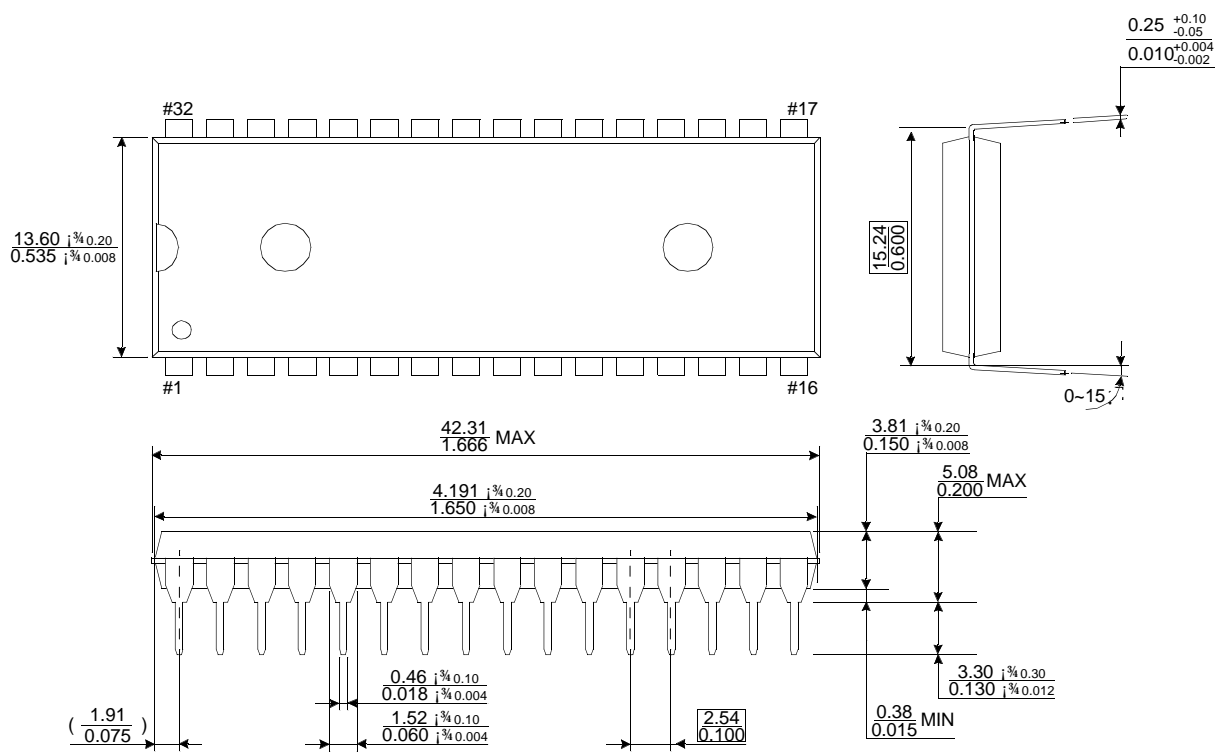
FUNCTIONAL DESCRIPTION

$\overline{CS_1}$	$\overline{CS_2}$	\overline{WE}	\overline{OE}	Mode	I/O Pin	Current Mode
H	X	X	X	Power Down	High-Z	ISB,ISB1
X	L	X	X	Power Down	High-Z	ISB,ISB1
L	H	H	H	Output Disable	High-Z	Icc
L	H	H	L	Read	Dout	Icc
L	H	L	X	Write	Din	Icc

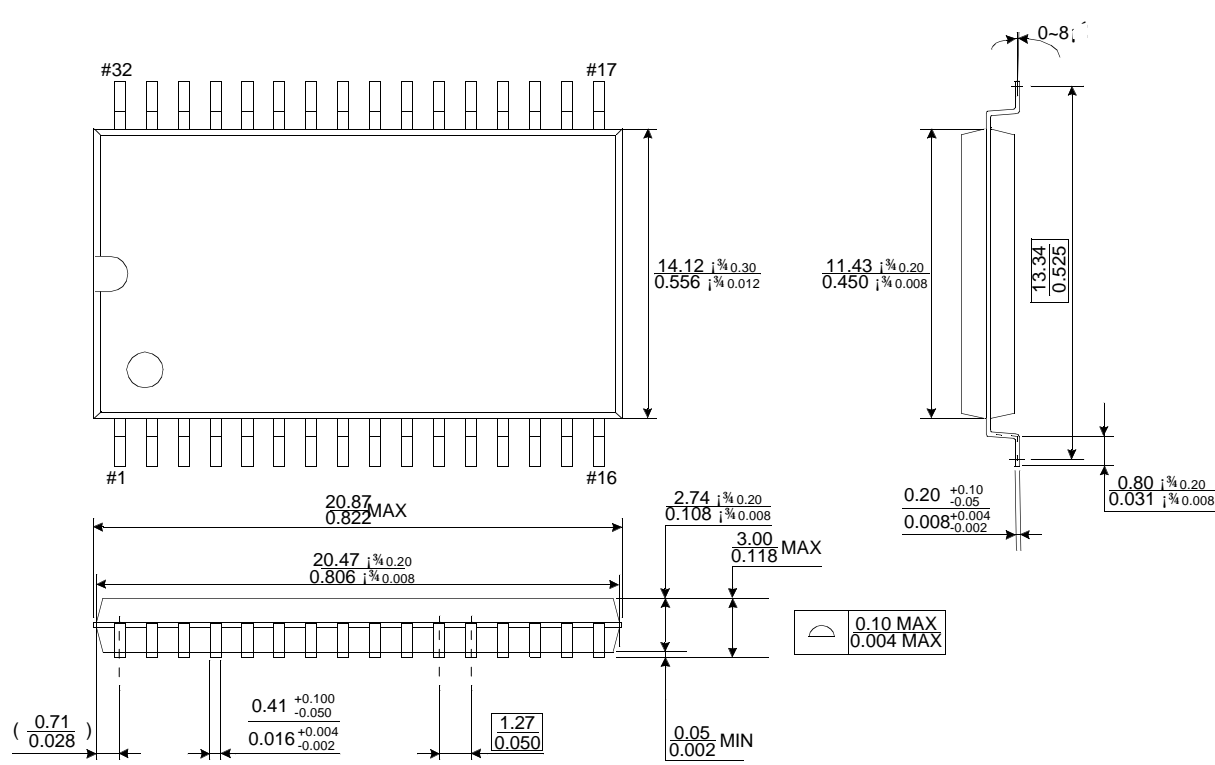
* X means don't care

PACKAGE DIMENSIONS
Units :MillimeterS(Inches)

32 DUAL INLINE PACKAGE (600mil)

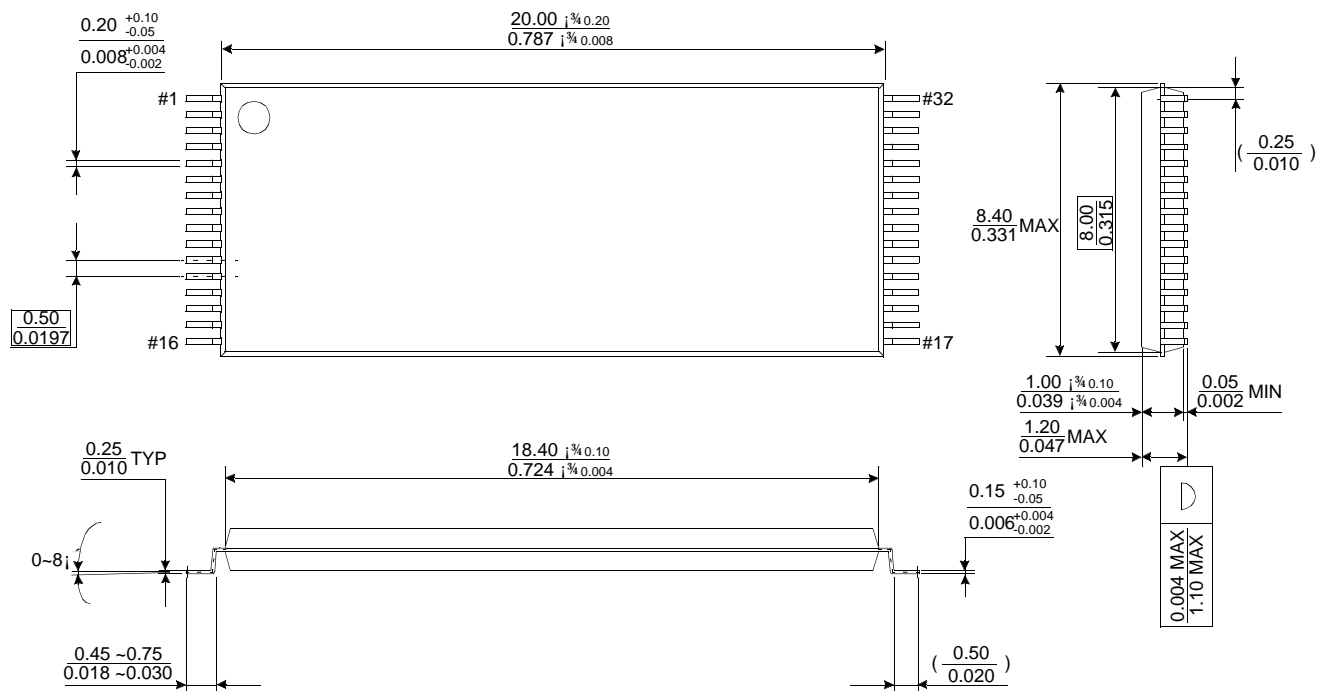


32 PLASTIC SMALL OUTLINE PACKAGE (525mil)



PACKAGE DIMENSIONS
 Units :MillimeterS(Inches)

32 THIN SMALL OUTLINE PACKAGE TYPE I (0820F)



32 THIN SMALL OUTLINE PACKAGE TYPE I (0820R)

